

# A2P2020

## 50 TO 2000 MHz SMA CASCADED AMPLIFIER

*Typical Values*

	<b>A2P2020</b>
<b>High Gain</b>	27.5 dB
<b>Low Noise Figure</b>	5.1 dB
<b>High Output Level</b>	+29.5 dBm
<b>High Third Order I.P.</b>	+41 dBm
<b>High Reverse Isolation</b>	52 dB
<b>High Performance Thin Film</b>	
<b>Power Pack SMA Package</b>	

### SPECIFICATIONS\*

Parameter	Typical	Guaranteed	
		0 to 50 °C	-55 to +85 °C
Frequency (Min.)	30-2100 MHz	50-2000 MHz	50-2000 MHz
Small Signal Gain (Min.)	27.5 dB	25.5 dB	24.5 dB
Gain Flatness (Max.)	±0.5 dB	±0.7 dB	±0.8 dB
Noise Figure (Max.)	5.1 dB	7.0 dB	7.5 dB
SWR (Max.)	Input/Output	1.7:1	1.9:1
Power Output (Min.) @ 1dB comp.	+29.5 dBm	+29.0 dBm	+28.5† dBm
Reverse Isolation	52 dB	—	—
DC Current (Max.)	620 mA	635 mA	650 mA

\* Measured in a 50-ohm system at +15 Vdc unless otherwise specified.

† Indicates minimum temperature at -55/+71 °C.

### INTERMODULATION PERFORMANCE

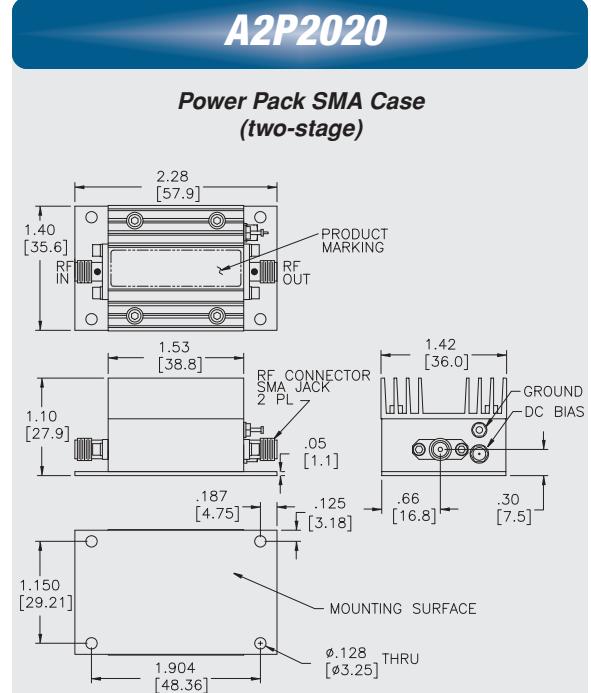
Typical @ 25 °C	<b>A2P2020</b>
Second Order Harmonic Intercept Point	+52 dBm
Second Order Two Tone Intercept Point	+55 dBm
Third Order Two Tone Intercept Point	+41 dBm

### ABSOLUTE MAXIMUM RATINGS

Storage Temperature	-62 to +125 °C
Maximum Case Temperature	+110 °C
Maximum DC Voltage	+17 Volts
Maximum Continuous RF Input Power	+22 dBm <sup>1</sup>
Maximum Short Term Input Power (1 Minute Max.)	200 Milliwatts
Maximum Peak Power (3 µsec Max.)	0.5 Watt
Burn-in Temperature	+85 °C
Thermal Resistance <sup>2</sup> (θ <sub>jc</sub> )	+10 °C/Watt
Junction Temperature Rise Above Case (T <sub>jC</sub> )	+57.8 °C

<sup>1</sup> If no load on output; decrease input power (no damage) by 10 dBm.

<sup>2</sup> Thermal resistance is based on total power dissipation.



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#### Power Pack SMA Case (two-stage)

DIMENSIONS ARE IN INCHES [MILLIMETERS]